











SN54AHCT573, SN74AHCT573

SCLS243O - OCTOBER 1995-REVISED SEPTEMBER 2014

SNx4AHCT573 Octal Transparent D-Type Latches With 3-State Outputs

Features

- Inputs are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- On Products Compliant to MIL-PRF-38535, All Parameters Are Tested Unless Otherwise Noted. On All Other Products, Production Processing Does Not Necessarily Include Testing of All Parameters.
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

Applications

- Servers
- PCs and Notebooks
- **Network Switches**
- Wearable Health and Fitness Devices
- Telecom Infrastructures
- Electronic Points of Sale

3 Description

The SNx4AHCT573 devices are octal transparent Dtype latches. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is low, the Q outputs are latched at the logic levels of the D inputs.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	SSOP (20)	7.20 mm × 5.30 mm		
	TVSOP (20)	5.00 mm × 4.40 mm		
SNx4AHCT573	SOIC (20)	12.80 mm × 7.50 mm		
	PDIP (20)	25.40 mm × 6.35 mm		
	TSSOP (20)	6.50 mm × 4.40 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

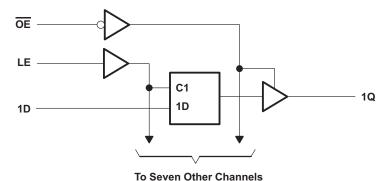




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5 Revision History

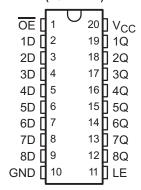
CI	hanges from Revision N (July 2003) to Revision O	Page
•	Updated document to new TI data sheet format.	1
•	Deleted Ordering Information table.	1
•	Added Military Disclaimer to Features list.	1
•	Added Applications.	1
•	Added Pin Functions table	3
•	Added Handling Ratings table.	4
•	Changed MAX operating temperature to 125°C in Recommended Operating Conditions table	
•	Added Thermal Information table.	5
•		
•	Added –40°C to 125°C temperature range for SN74AHCT573 in Timing Requirements table	5
•	Added Typical Characteristics.	6
•	Added Detailed Description section	8
•	Added Application and Implementation section	
•	Added Power Supply Recommendations and Layout sections	

Product Folder Links: SN54AHCT573 SN74AHCT573

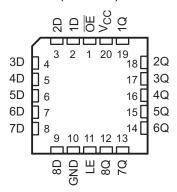


6 Pin Configuration and Functions

SN54AHCT573 . . . J OR W PACKAGE SN74AHCT573 . . . DB, DGV, DW, N, NS, OR PW PACKAGE (TOP VIEW)



SN54AHCT573 . . . FK PACKAGE (TOP VIEW)



Pin Functions

	PIN	1/0	PEGADIDATION
NO.	NAME	I/O	DESCRIPTION
1	ŌĒ	I	Output Enable
2	1D	1	1D Input
3	2D	1	2D Input
4	3D	1	3D Input
5	4D	1	4D Input
6	5D	1	5D Input
7	6D	1	6D Input
8	7D	1	7D Input
9	8D	I	8D Input
10	GND	_	Ground
11	LE	1	Latch Enable
12	8Q	0	8Q Output
13	7Q	0	7Q Output
14	6Q	0	6Q Output
15	5Q	0	5Q Output
16	4Q	0	4Q Output
17	3Q	0	3Q Output
18	2Q	0	2Q Output
19	1Q	0	1Q Output
20	V _{CC}	_	Power Pin

Product Folder Links: SN54AHCT573 SN74AHCT573

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7 Specifications

7.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	7	٧
V_{I}	Input voltage range ⁽²⁾		-0.5	7	٧
Vo	Output voltage range (2)		-0.5	$V_{CC} + 0.5$	٧
I _{IK}	Input clamp current	V ₁ < 0		-20	mA
I _{OK}	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}		±25	mA
	Continuous current through V _{CC} or GND			±75	mA

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

			MIN	MAX	UNIT	
T _{stg}	Storage temperature rang	ie e	- 65	150	Ô	
V	Flootrootatio dicabaras	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	0	2000	V	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	0	1000	V	

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

		SN54AHC	T573	SN74AHCT573		UNIT
		MIN	MAX	MIN	MAX	UNIT
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		8.0	V
VI	Input voltage	0	5.5	0	5.5	V
V_{O}	Output voltage	0	V_{CC}	0	V_{CC}	V
I _{OH}	High-level output current		-8		-8	mA
I_{OL}	Low-level output current		8		8	mA
Δt/Δν	Input transition rise or fall rate		20		20	ns/V
T _A	Operating free-air temperature	– 55	125	-40	125	°C

All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).

Product Folder Links: SN54AHCT573 SN74AHCT573

²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.4 Thermal Information

		SN74AHCT573							
	THERMAL METRIC ⁽¹⁾	DW	DB	DGV	N	NS	PW	UNIT	
		20 PINS							
$R_{\theta JA}$	Junction-to-ambient thermal resistance	79.4	97.9	117.2	53.3	79.2	103.3		
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	45.7	59.6	32.7	40.0	45.7	37.8		
$R_{\theta JB}$	Junction-to-board thermal resistance	46.9	53.1	58.7	34.2	46.8	54.3	°C/W	
ΨЈТ	Junction-to-top characterization parameter	18.7	21.3	1.15	26.4	19.3	2.9	-C/VV	
ΨЈВ	Junction-to-board characterization parameter	46.5	52.7	58.0	34.1	46.4	53.8		
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	n/a	n/a	n/a		

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	T _A = 25°C		SN54AHCT573		SN74AHCT573		-40°C to 125°C SN74AHCT573		UNIT	
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	I _{OH} = -50 μA	45.77	4.4	4.5		4.4		4.4		4.4		V
V_{OH}	I _{OH} = −8 mA	4.5 V	3.94			3.8		3.8		3.8		V
V _{OL}	I _{OL} = 50 μA	45.77			0.1		0.1		0.1		0.1	
	I _{OL} = 8 mA	4.5 V			0.36		0.44		0.44		0.44	V
I _I	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1 ⁽¹⁾		±1		<u>+</u> 2	μΑ
I _{OZ}	V _O = V _{CC} or GND	5.5 V			±0.25		±2.5		±2.5		±2.5	μΑ
I _{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40		40	μΑ
ΔI _{CC} ⁽²⁾	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5		1.5	mA
C _i	V _I = V _{CC} or GND	5 V		2.5	10				10		10	pF
C _o	V _O = V _{CC} or GND	5 V		3								pF

7.6 Timing Requirements

over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 2)

PARAMETER		T _A = 25°C		SN54AHCT573		SN74AHCT573		-40°C to 125°C SN74AHCT573		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _w	Pulse duration, LE high	5		5		5		5		ns
t _{su}	Setup time, data before LE↓	3.5		3.5		3.5		3.5		ns
t _h	Hold time, data after LE↓	1.5		1.5		1.5		1.5		ns

Product Folder Links: SN54AHCT573 SN74AHCT573

On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$. This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or V_{CC} .



7.7 Switching Characteristics

over recommended operating free-air temperature range, $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$ (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO	LOAD CAPACITANCE	T _A = 2	T _A = 25°C SN54AHCT57		CT573	SN74AHCT573		T _A = -40°C to 125°C SN74AHCT573		UNIT		
	(IIII O1)	(OUTPUT)	CAPACITANCE	MIN TY	Р МАХ	MIN	MAX	MIN	MAX	MIN	MAX			
t _{PLH}	D	Q	C ₁ = 15 pF	4.2	¹⁾ 6 ⁽¹⁾	1 (1)	6.5 ⁽¹⁾	1	6.5	1	7			
t _{PHL}	ט	Q	O _L = 15 pr	5.1	¹⁾ 7 ⁽¹⁾	1 ⁽¹⁾	9 ⁽¹⁾	1	9	1	9.5	ns		
t _{PLH}	LE	Q	0 15 25	4.7	1) 6.5 ⁽¹⁾	1 (1)	7.5 ⁽¹⁾	1	7.5	1	8			
t _{PHL}	LE	Q	$C_L = 15 pF$	5.6	¹⁾ 7.5 ⁽¹⁾	1 ⁽¹⁾	9 ⁽¹⁾	1	9	1	9.5	ns		
t _{PZH}	ŌĒ	Q	0 15 5	4.1	1) 6.5 ⁽¹⁾	1 (1)	7 ⁽¹⁾	1	7	1	8			
t _{PZL}	OE	OE G	Q	$C_L = 15 pF$	5.5	¹⁾ 7.5 ⁽¹⁾	1 (1)	9 ⁽¹⁾	1	10	1	11	ns	
t _{PHZ}	ŌĒ	OF.	OF.	Q	0 15 5	5.5	1) 8 ⁽¹⁾	1 (1)	11 ⁽¹⁾	1	11	1	12	ns
t_{PLZ})L Q	$C_L = 15 pF$	5.4	1) 8 ⁽¹⁾	1 (1)	9.5 ⁽¹⁾	1	9.5	1	10.5	110		
t _{PLH}	D	Q	C 50 pE	5	2 7	1	7.5	1	7.5	1	8.5	no		
t _{PHL}	D	Q	$C_L = 50 pF$	6	1 8	1	10	1	10	1	10.5	ns		
t _{PLH}	LE	Q	C ₁ = 50 pF	5	7 7.5	1	8.5	1	8.5	1	9.5	no		
t _{PHL}	LE	Q	O _L = 50 pr	6	6 8.5	1	10	1	10	1	10.5	ns		
t_{PZH}	ŌĒ	Q	C 50 pF	5	1 7.5	1	8	1	8	1	9	no		
t _{PZL}	OE	Q	$C_L = 50 \text{ pF}$	6	5 8.5	1	11	1	11	1	11.5	ns		
t _{PHZ}	ŌĒ	OE.	Q	C = 50 pE	6	7 9	1	12	1	12	1	12.5	ne	
t_{PLZ}		Q	C _L = 50 pF	6			10.5	1	10.5	1	11.5	ns		
t _{sk(o)}			C _L = 50 pF		1.5 ⁽²⁾				1.5			ns		

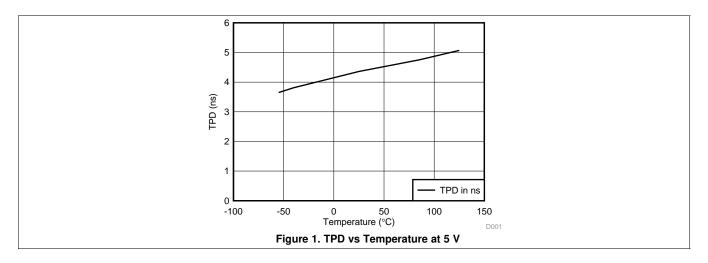
⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.8 Operating Characteristics

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$

00	PARAMETER	TEST CO	TYP	UNIT	
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	16	pF

7.9 Typical Characteristics



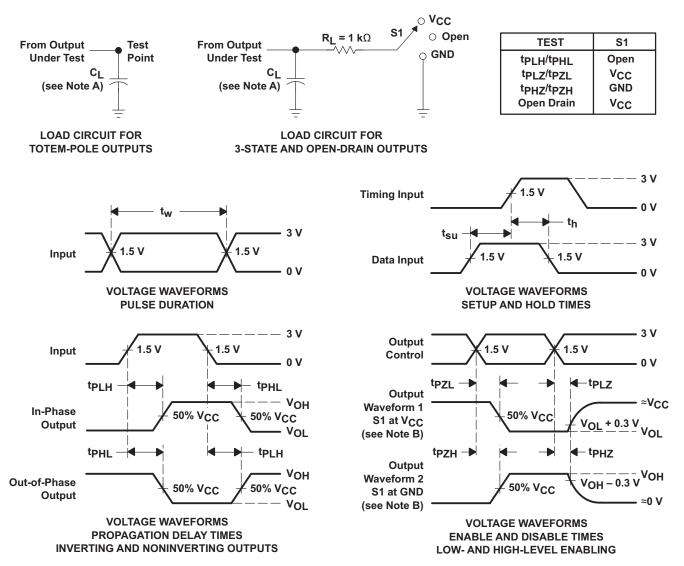
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⁽²⁾ On products compliant to MIL-PRF-38535, this parameter does not apply.



8 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , $t_f \leq$ 3 ns. $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

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9 Detailed Description

9.1 Overview

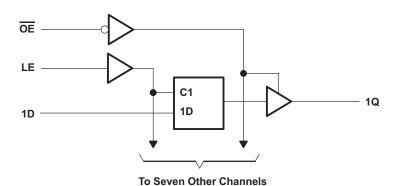
The SNx4AHCT573 devices are octal transparent D-type latches. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is low, the Q outputs are latched at the logic levels of the D inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pull-up components.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

9.2 Functional Block Diagram



9.3 Feature Description

- TTL inputs
 - Lowered switching threshold allows up translation 3.3 V to 5 V
- Slow edges reduce output ringing

9.4 Device Functional Modes

Table 1. Function Table (Each Latch)

	INPUTS	OUTPUT	
OE	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	Χ	Q_0
Н	Χ	Χ	Z

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10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The SN74AHCT573 is a low-drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The input switching levels have been lowered to accommodate TTL inputs of 0.8-V V_{IL} and 2-V V_{IH} . This feature makes the device ideal for translating up from 3.3 V to 5 V. Figure 4 shows this type of translation.

10.2 Typical Application

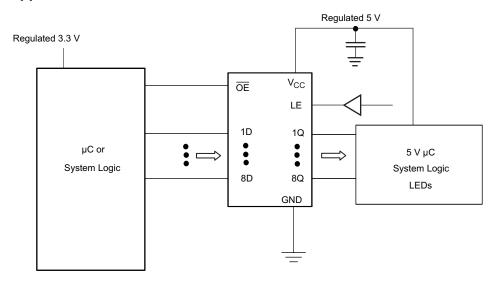


Figure 3. Typical Application Schematic

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads; therefore, routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

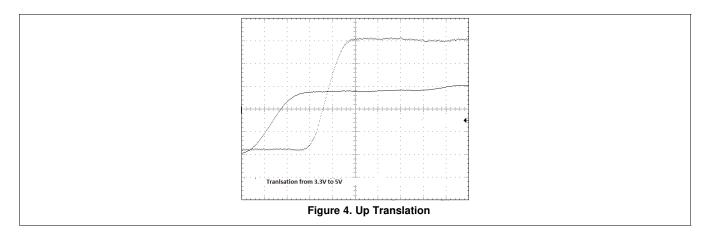
- 1. Recommended input conditions
 - Rise time and fall time specs: See (Δt/ΔV) in the Recommended Operating Conditions table.
 - Specified High and low levels: See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}.
- 2. Recommend output conditions
 - Load currents should not exceed 25 mA per output and 75 mA total for the part.
 - Outputs should not be pulled above V_{CC}.

Product Folder Links: SN54AHCT573 SN74AHCT573



Typical Application (continued)

10.2.3 Application Curves



Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the Recommended Operating Conditions table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, $0.1~\mu F$ bypass capacitor is recommended. If there are multiple V_{CC} pins, $0.01~\mu F$ or $0.022~\mu F$ is recommended for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1 µF and 1 µF are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

12 Layout

12.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified in Figure 5 are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC}; whichever makes more sense or is more convenient. It is generally acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the IO's so they cannot float when disabled.

12.2 Layout Example

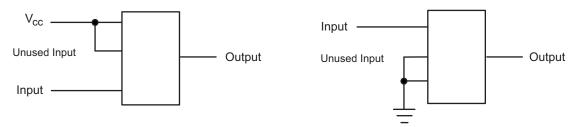


Figure 5. Layout Diagram

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13 Device and Documentation Support

13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54AHCT573	Click here	Click here	Click here	Click here	Click here
SN74AHCT573	Click here	Click here	Click here	Click here	Click here

13.2 Trademarks

All trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN54AHCT573 SN74AHCT573





28-Nov-2015

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9685501Q2A	NRND	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9685501Q2A SNJ54AHCT 573FK	
5962-9685501QRA	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9685501QR A SNJ54AHCT573J	Samples
5962-9685501QSA	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9685501QS A SNJ54AHCT573W	Samples
SN74AHCT573DBLE	OBSOLETE	SSOP	DB	20		TBD	Call TI	Call TI	-40 to 85		
SN74AHCT573DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB573	Samples
SN74AHCT573DGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB573	Samples
SN74AHCT573DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT573	Samples
SN74AHCT573DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT573	Samples
SN74AHCT573DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT573	Samples
SN74AHCT573DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT573	Samples
SN74AHCT573N	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHCT573N	Samples
SN74AHCT573NE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHCT573N	Samples
SN74AHCT573PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB573	Samples
SN74AHCT573PWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB573	Samples
SN74AHCT573PWLE	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	-40 to 85		
SN74AHCT573PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	HB573	Samples



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PACKAGE OPTION ADDENDUM

28-Nov-2015

Orderable Device	Status	Package Type	Package Drawing		Package Qty		Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
SN74AHCT573PWRE4	ACTIVE	TSSOP	PW	20	2000	(2) Green (RoHS & no Sb/Br)	(6) CU NIPDAU	(3) Level-1-260C-UNLIM	-40 to 125	(4/5) HB573	Samples
SN74AHCT573PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB573	Samples
SNJ54AHCT573FK	NRND	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9685501Q2A SNJ54AHCT 573FK	
SNJ54AHCT573J	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9685501QR A SNJ54AHCT573J	Samples
SNJ54AHCT573W	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9685501QS A SNJ54AHCT573W	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.





28-Nov-2015

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54AHCT573, SN74AHCT573:

Catalog: SN74AHCT573

Automotive: SN74AHCT573-Q1, SN74AHCT573-Q1

Military: SN54AHCT573

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHCT573DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74AHCT573DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHCT573DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHCT573PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AHCT573PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AHCT573PWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHCT573DBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74AHCT573DGVR	TVSOP	DGV	20	2000	367.0	367.0	35.0
SN74AHCT573DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHCT573PWR	TSSOP	PW	20	2000	364.0	364.0	27.0
SN74AHCT573PWR	TSSOP	PW	20	2000	367.0	367.0	38.0
SN74AHCT573PWRG4	TSSOP	PW	20	2000	367.0	367.0	38.0

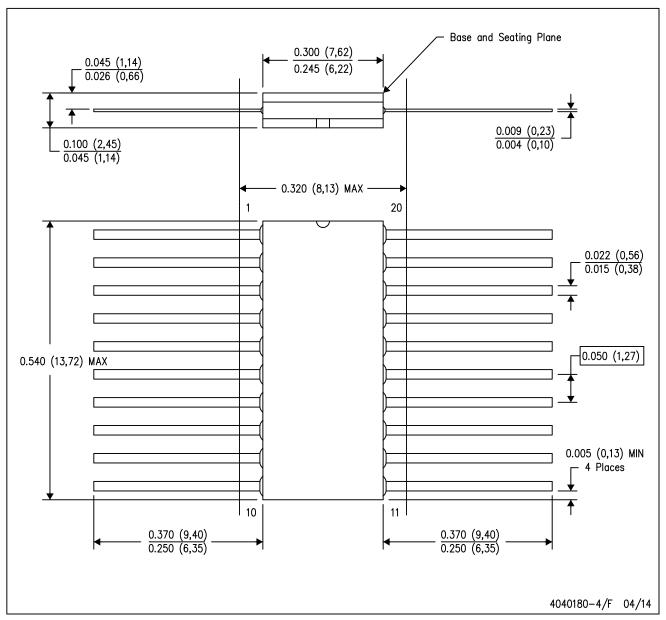
14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

 D. Index point is provided on cap for terminal identification only.

 E. Falls within Mil—Std 1835 GDFP2—F20



FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

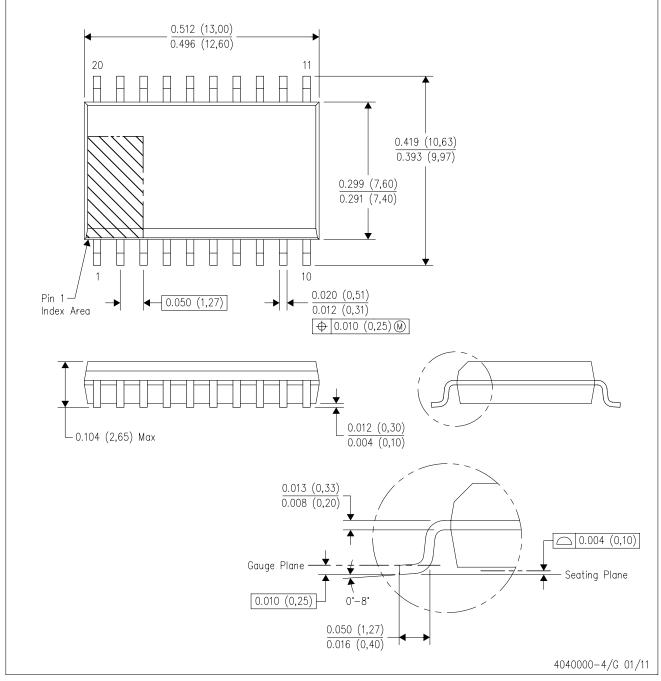
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



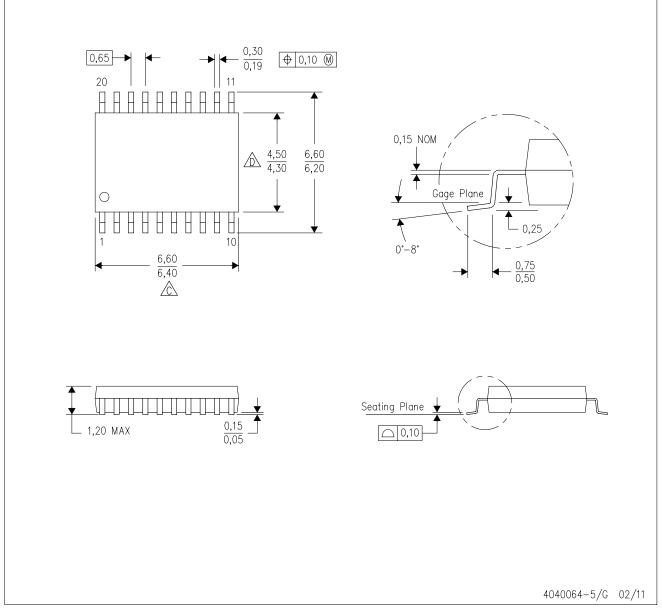
NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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Products	Applications

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